Functional Safety Information AFE539F1-Q1 Functional Safety FIT Rate, FMD and Pin FMA

TEXAS INSTRUMENTS

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1 Overview

This document contains information for the AFE539F1-Q1 (RTE package) to aid in a functional safety system design. Information provided are:

- Functional safety failure in time (FIT) rates of the semiconductor component estimated by the application of industry reliability standards
- Component failure modes and their distribution (FMD) based on the primary function of the device
- Pin failure mode analysis (pin FMA)

Figure 1-1 shows the device functional block diagram for reference.

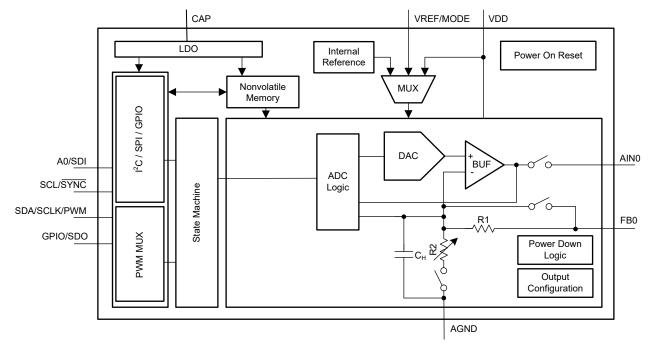


Figure 1-1. Functional Block Diagram

The AFE539F1-Q1 was developed using a quality-managed development process, but was not developed in accordance with the IEC 61508 or ISO 26262 standards.

2 Functional Safety Failure In Time (FIT) Rates

This section provides functional safety failure in time (FIT) rates for the AFE539F1-Q1 based on two different industry-wide used reliability standards:

- Table 2-1 provides FIT rates based on IEC TR 62380 / ISO 26262 part 11
- Table 2-2 provides FIT rates based on the Siemens Norm SN 29500-2

Table 2-1. Component Failure Rates per IEC TR 62380 / ISO 26262 Part 11

FIT IEC TR 62380 / ISO 26262	FIT (Failures Per 10 ⁹ Hours)			
Total component FIT rate	8			
Die FIT rate	2			
Package FIT rate	6			

The failure rate and mission profile information in Table 2-1 comes from the reliability data handbook IEC TR 62380 / ISO 26262 part 11:

- Mission profile: Motor control from table 11
- Power dissipation: 50 mW
- Climate type: World-wide table 8
- Package factor (lambda 3): Table 17b
- Substrate material: FR4
- EOS FIT rate assumed: 0 FIT

Table 2-2. Component Failure Rates per Siemens Norm SN 29500-2

Table	Category	Reference FIT Rate	Reference Virtual T _J
5	CMOS, BICMOS Digital, analog, or mixed	60 FIT	70°C

The reference FIT rate and reference virtual T_J (junction temperature) in Table 2-2 come from the Siemens Norm SN 29500-2 tables 1 through 5. Failure rates under operating conditions are calculated from the reference failure rate and virtual junction temperature using conversion information in SN 29500-2 section 4.



3 Failure Mode Distribution (FMD)

The failure mode distribution estimation for the AFE539F1-Q1 in Table 3-1 comes from the combination of common failure modes listed in standards such as IEC 61508 and ISO 26262, the ratio of sub-circuit function size and complexity, and from best engineering judgment.

The failure modes listed in this section reflect random failure events and do not include failures resulting from misuse or overstress.

Die Failure Modes	Failure Mode Distribution (%)
Digital core, state machine, and interface failure	51
NVM (EEPROM/OTP) retention loss	17
Reference failure	5
POR failure	5
ADC failure	22

Table 3-1. Die Failure Modes and Distribution



4 Pin Failure Mode Analysis (Pin FMA)

This section provides a failure mode analysis (FMA) for the pins of the AFE539F1-Q1. The failure modes covered in this document include the typical pin-by-pin failure scenarios:

- Pin short-circuited to ground (see Table 4-2)
- Pin open-circuited (see Table 4-3)
- Pin short-circuited to an adjacent pin (see Table 4-4)
- Pin short-circuited to supply (see Table 4-5)

Table 4-2 through Table 4-5 also indicate how these pin conditions can affect the device as per the failure effects classification in Table 4-1.

Class	Failure Effects
A	Potential device damage that affects functionality.
В	No device damage, but loss of functionality.
C	No device damage, but performance degradation.
D	No device damage, no impact to functionality or performance.

Table 4-1. TI Classification of Failure Effects

Figure 4-1 shows the AFE539F1-Q1 pin diagram. For a detailed description of the device pins, see the *Pin Configuration and Functions* section in the AFE539F1-Q1 data sheet.

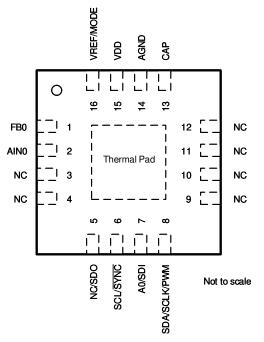


Figure 4-1. Pin Diagram

Following are the assumptions of use and the device configuration assumed for the pin FMA in this section:

• All the pin FMA analysis are described based on Figure 1-1.

Pin Name	Pin No.	Description of Potential Failure Effects	Failure Effect Class
FB0	1	ADC and PWM duty cycle performance degradation	С
AIN0	2	Loss of ADC functionality and PWM output duty cycle is stuck to maximum duty cycle	В
NC	3	No change in functionality or performance	D
NC	4	No change in functionality or performance	D
NC/SDO	5	Loss of SDO functionality and read back data is not available	В
SCL/SYNC	6	Loss of communication with the device	В
A0/SDI	7	Loss of communication with the device	В
SDA/SCLK/PWM	8	Loss of communication and PWM functionality with the device	В
NC	9	No change in functionality or performance	D
NC	10	No change in functionality or performance	D
NC	11	No change in functionality or performance	D
NC	12	No change in functionality or performance	D
CAP	13	Loss of functionality, device enters short circuit protection, power consumption increases	В
AGND	14	No change in functionality or performance	D
VDD	15	Complete loss of functionality, no device damage	В
VREF/MODE	16	Loss of core DAC functionality and PWM mode	В

Table 4-2. Pin FMA for Device Pins Short-Circuited to Ground

Table 4-3. Pin FMA for Device Pins Open-Circuited

Pin Name	Pin No.	Description of Potential Failure Effects	Failure Effect Class
FB0	1	ADC and PWM duty cycle performance degradation	С
AIN0	2	ADC input is not available and PWM output duty cycle will be corrupted	В
NC	3	No change in functionality or performance	D
NC	4	No change in functionality or performance	D
NC/SDO	5	Loss of SDO functionality and read back data is not available	В
SCL/SYNC	6	Loss of communication with the device	В
A0/SDI	7	Loss of communication with the device	В
SDA/SCLK/PWM	8	Loss of communication and PWM functionality is not available	В
NC	9	No change in functionality or performance	D
NC	10	No change in functionality or performance	D
NC	11	No change in functionality or performance	D
NC	12	No change in functionality or performance	D
САР	13	Open-circuited pin can cause damage to the low-voltage digital core and NVM supplied by the internal LDO	A
AGND	14	Complete loss of functionality, no device damage	В
VDD	15	Complete loss of functionality, no device damage	В
VREF/MODE	16	Loss of core DAC functionality and PWM mode	В

Pin Name	Pin No.	Shorted to	Description of Potential Failure Effects	Failure Effect Class
	4	VREF/MODE	Short to corner pin is not expected	D
FB0	1	AIN0	ADC and PWM duty cycle performance degradation	С
AINO	•	FB0	ADC and PWM duty cycle performance degradation	С
	2	NC	No change in functionality or performance	D
		AIN0	No change in functionality or performance	D
NC	3	NC	No change in functionality or performance	D
NG	4	NC	No change in functionality or performance	D
NC	4	NC/SDO	Short to corner pin is not expected	D
		NC	Short to corner pin is not expected	D
NC/SDO	5	SCL/SYNC	Loss of communication with the device, SDO functionality and read back data is not available	В
SCL/SYNC 6	6	NC/SDO	Loss of communication with the device, SDO functionality and read back data is not available	В
		A0/SDI	Loss of communication with the device	В
	7	SCL/SYNC	Loss of communication with the device	В
A0/SDI	7	SDA/SCLK/PWM	Loss of communication and PWM functionality with the device	В
	8	A0/SDI	Loss of communication and PWM functionality with the device	В
SDA/SCLK/PWM	0	NC	Short to corner pin is not expected	D
NC	9	SDA/SCLK/PWM	Short to corner pin is not expected	D
NC	9	NC	No change in functionality or performance	D
NC	10	NC	No change in functionality or performance	D
NC	10	NC	No change in functionality or performance	D
NC	11	NC	No change in functionality or performance	D
NC	11	NC	No change in functionality or performance	D
NG	40	NC	No change in functionality or performance	D
NC	12	CAP	Short to corner pin is not expected	D
CAD	10	NC	Short to corner pin is not expected	D
CAP	13	AGND	Device enters short circuit protection, power consumption increases	В
	4.4	CAP	Device enters short circuit protection, power consumption increases	В
AGND	14	VDD	Complete loss of functionality, no device damage	В
	15	AGND	Complete loss of functionality, no device damage	В
VDD		VREF/MODE	Loss of partial functionality that includes I2C/SPI communication with device, external reference mode and internal reference mode	В
VREF/MODE	16	VDD	Loss of partial functionality that includes I2C/SPI communication with device, external reference mode and internal reference mode	В
		FB0	Short to corner pin is not expected	D

Table 4-4. Pin FMA for Device Pins Short-Circuited to Adjacent Pin

Pin Name	Pin No.	Description of Potential Failure Effects	Failure Effect Class
FB0	1	ADC and PWM duty cycle performance degradation	С
AIN0	2	Loss of ADC functionality and PWM output duty cycle is stuck to minimum duty cycle	В
NC	3	No change in functionality or performance	D
NC	4	No change in functionality or performance	D
NC/SDO	5	Loss of SDO functionality and read back data will be corrupted	В
SCL/SYNC	6	Loss of communication with the device	В
A0/SDI	7	Loss of communication with the device	В
SDA/SCLK/PWM	8	Loss of communication and PWM functionality with the device	В
NC	9	No change in functionality or performance	D
NC	10	No change in functionality or performance	D
NC	11	No change in functionality or performance	D
NC	12	No change in functionality or performance	D
CAP	13	Shorting to VDD pin can cause damage to the low-voltage digital core and NVM supplied by the internal LDO	А
AGND	14	Complete loss of functionality, no device damage	В
VDD	15	No change in functionality or performance	D
VERF/MODE	16	Loss of partial functionality that includes I2C/SPI communication with device, external reference mode	В

Table 4-5. Pin FMA for Device Pins Short-Circuited to supply

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